# **DatasheetArchive.**....

# **Request For Quotation**

Order the parts you need from our real-time inventory database. Simply complete a request for quotation form with your part information and a sales representative will respond to you with price and availability.

**Request For Quotation** 

Your free datasheet starts on the next page.

More datasheets and data books are available from our homepage: http://www.datasheetarchive.com



# BUH1215 HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

- STMicroelectronics PREFERRED SALESTYPE
- HIGH VOLTAGE CAPABILITY
- VERY HIGH SWITCHING SPEED

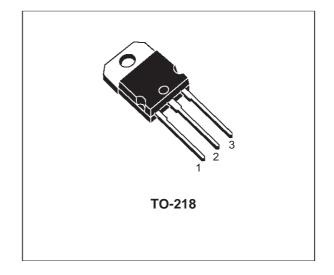
# **APPLICATIONS:**

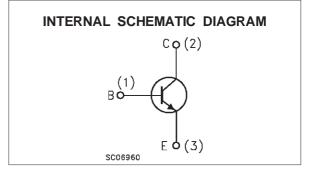
 HORIZONTAL DEFLECTION FOR COLOUR TV AND MONITORS

## DESCRIPTION

The BUH1215 is manufactured using Multiepitaxial Mesa technology for cost-effective high performance and uses a Hollow Emitter structure to enhance switching speeds.

The BUH series is designed for use in horizontal deflection circuits in televisions and monitors.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>СВО</sub>	Collector-Base Voltage $(I_E = 0)$	1500	V
V <sub>CEO</sub>	Collector-Emitter Voltage $(I_B = 0)$	700	V
V <sub>EBO</sub>	Emitter-Base Voltage (I <sub>C</sub> = 0)	10	V
Ic	Collector Current	16	Α
Ісм	Collector Peak Current (t <sub>p</sub> < 5 ms)	22	Α
Ι <sub>Β</sub>	Base Current	9	Α
I <sub>BM</sub>	Base Peak Current (t <sub>p</sub> < 5 ms)	12	Α
Ptot	Total Dissipation at $T_c = 25 \ ^{\circ}C$	200	W
T <sub>stg</sub>	Storage Temperature	-65 to 150	°C
Tj	Max. Operating Junction Temperature	150	°C

January 1999

# THERMAL DATA

R <sub>thj-case</sub> Thermal Resistance Junction-case Max 0.63 °C/W
--

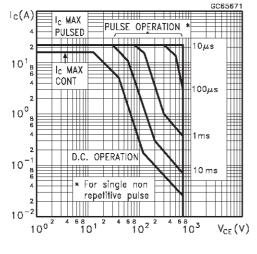
# **ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25 \,^{\circ}C$ unless otherwise specified)

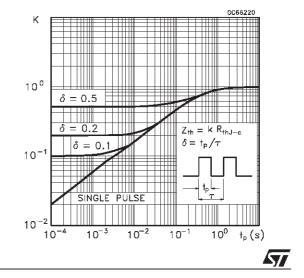
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I <sub>CES</sub>	Collector Cut-off Current ( $V_{BE} = 0$ )	$V_{CE} = 1500 V$ $V_{CE} = 1500 V$ $T_j = 125 °C$			0.2 2	mA mA
I <sub>EBO</sub>	Emitter Cut-off Current $(I_C = 0)$	$V_{EB} = 5 V$			100	μA
$V_{\text{CEO}(\text{sus})}$	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 100 mA	700			V
$V_{\text{EBO}}$	Emitter-Base Voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 10 mA	10			V
$V_{CE(sat)^*}$	Collector-Emitter Saturation Voltage	$I_{\rm C} = 12$ A $I_{\rm B} = 2.4$ A			1.5	V
$V_{BE(sat)^*}$	Base-Emitter Saturation Voltage	$I_{\rm C} = 12 \text{ A}$ $I_{\rm B} = 2.4 \text{ A}$			1.5	V
h <sub>FE</sub> *	DC Current Gain		7 5	10	14	
t <sub>s</sub> t <sub>f</sub>	RESISTIVE LOAD Storage Time Fall Time			1.5 110		μs ns
t <sub>s</sub> t <sub>f</sub>	INDUCTIVE LOAD Storage Time Fall Time	$ \begin{array}{ll} IC = 12 \ A & f = 31250 \ Hz \\ I_{B1} = 2 \ A & I_{B2} = -1.5 \ A \\ V_{ceflyback} = 1050 \ sin \bigg( \frac{\pi}{5} \ 10^6 \bigg) t & V \end{array} $		4 220		μs ns
t <sub>s</sub> t <sub>f</sub>	INDUCTIVE LOAD Storage Time Fall Time	$ \begin{array}{ll} I_{C} = 6 \ A & f = 64 \ KHz \\ I_{B1} = 1 \ A & V_{BE(off)} = -2 \ A \\ V_{ceflyback} = 1200 \ sin\left(\frac{\pi}{5} \ 10^{6}\right) t & V \end{array} $		3.5 180		μs ns

\* Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

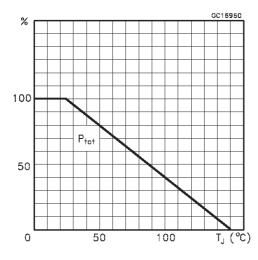
# Safe Operating Area

# **Thermal Impedance**

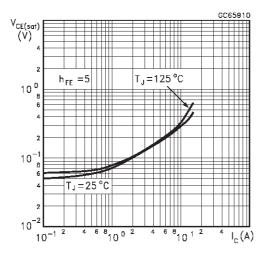




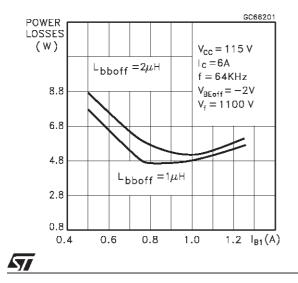
## **Derating Curve**



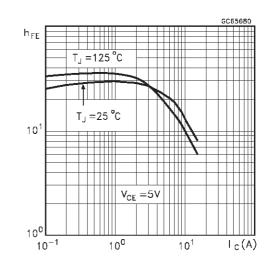
Collector Emitter Saturation Voltage



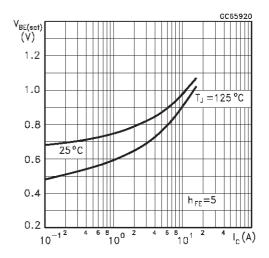
# Power Losses at 64 KHz



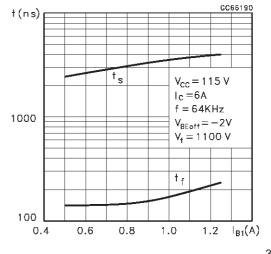
DC Current Gain



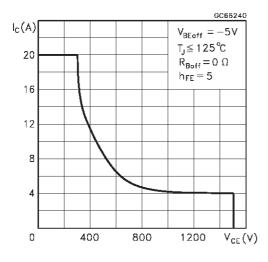
#### Base Emitter Saturation Voltage



Switching Time Inductive Load at 64 KHz (see figure 2)



#### **Reverse Biased SOA**



# **BASE DRIVE INFORMATION**

In order to saturate the power switch and reduce conduction losses, adequate direct base current  $I_{B1}$  has to be provided for the lowest gain  $h_{FE}$  at 100 °C (line scan phase). On the other hand, negative base current  $I_{B2}$  must be provided the transistor to turn off (retrace phase).

Most of the dissipation, especially in the deflection application, occurs at switch-off so it is essential to determine the value of  $I_{B2}$  which minimizes power losses, fall time  $t_f$  and, consequently,  $T_j$ . A new set of curves have been defined to give total power losses,  $t_s$  and  $t_f$  as a function of  $I_{B1}$  at 64 KHz scanning frequencies for

choosing the optimum negative drive. The test circuit is illustrated in figure 1.

The values of L and C are calculated from the following equations:

$$\frac{1}{2}L(I_{C})^{2} = \frac{1}{2}C(V_{CEfly})^{2}$$
$$\omega = 2\pi f = \frac{1}{\sqrt{LC}}$$

Where  $I_C$  = operating collector current,  $V_{CEfly}$ = flyback voltage, f= frequency of oscillation during retrace.

57

Figure 1: Inductive Load Switching Test Circuits.

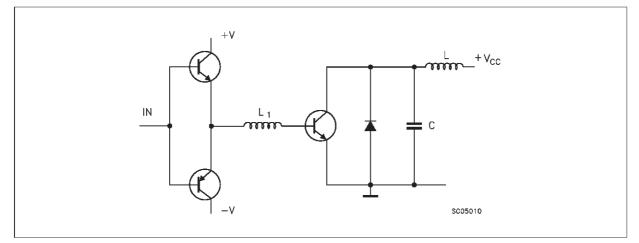
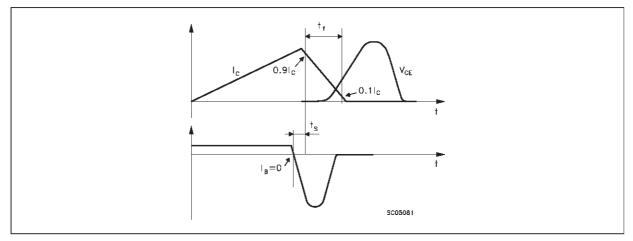
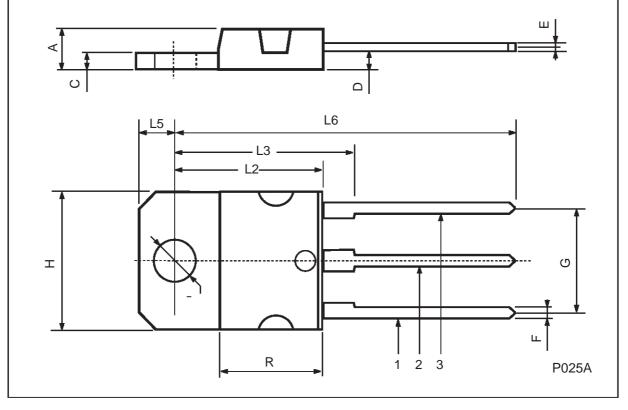


Figure 2: Switching Waveforms in a Deflection Circuit



DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	4.7		4.9	0.185		0.193	
С	1.17		1.37	0.046		0.054	
D		2.5			0.098		
E	0.5		0.78	0.019		0.030	
F	1.1		1.3	0.043		0.051	
G	10.8		11.1	0.425		0.437	
Н	14.7		15.2	0.578		0.598	
L2	_		16.2	-		0.637	
L3		18			0.708		
L5	3.95		4.15	0.155		0.163	
L6		31			1.220		
R	-		12.2	-		0.480	





6/7

57

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics. The ST logo is a trademark of STMicroelectronics

© 1999 STMicroelectronics - Printed in Italy - All Rights Reserved

STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - France - Germany - Italy - Japan - Korea - Malaysia - Malta - Mexico - Morocco - The Netherlands -Singapore - Spain - Sweden - Switzerland - Taiwan - Thailand - United Kingdom - U.S.A.

http://www.st.com

57